

NPN General - Purpose Amplifier

2N3904

Description

This device is designed as a general-purpose amplifier and switch. The useful dynamic range extends to 100 mA as a switch and to 100 MHz as an amplifier.

MAXIMUM RATINGS

(Values are at $T_A = 25^\circ\text{C}$ unless otherwise noted.) (Note 1, Note 2)

Symbol	Parameter	Value	Unit
V_{CEO}	Collector - Emitter Voltage	40	V
V_{CBO}	Collector - Base Voltage	60	V
V_{EBO}	Emitter - Base Voltage	6.0	V
I_C	Collector Current - Continuous	200	mA
T_J, T_{STG}	Operating and Storage Junction Temperature Range	-55 to +150	$^\circ\text{C}$

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

- These ratings are based on a maximum junction temperature of 150°C .
- These are steady-state limits. onsemi should be consulted on applications involving pulsed or low-duty cycle operations.

THERMAL CHARACTERISTICS

(Values are at $T_A = 25^\circ\text{C}$ unless otherwise noted.)

Symbol	Parameter	Max	Unit
P_D	Total Device Dissipation	625	mW
	Derate Above 25°C	5.0	mW/ $^\circ\text{C}$
$R_{\theta JC}$	Thermal Resistance, Junction to Case	83.3	$^\circ\text{C}/\text{W}$
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	200	$^\circ\text{C}/\text{W}$

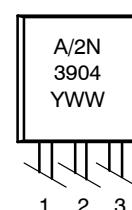


TO-92 3
CASE 135AN



TO-92 3
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CASE 135AR

MARKING DIAGRAM



1: Emitter
2: Base
3: Collector

A = Assembly Code
2N3904 = Device Code
YWW = Date Code

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 6 of this data sheet.

ELECTRICAL CHARACTERISTICS (Values are at $T_A = 25^\circ\text{C}$ unless otherwise noted.)

Symbol	Parametr	Conditions	Min	Max	Unit
OFF CHARACTERISTICS					
$V_{(BR)CEO}$	Collector – Emitter Breakdown Voltage	$I_C = 1.0\text{ mA}, I_B = 0$	40	–	V
$V_{(BR)CBO}$	Collector – Base Breakdown Voltage	$I_C = 10\text{ }\mu\text{A}, I_E = 0$	60	–	V
$V_{(BR)EBO}$	Emitter – Base Breakdown Voltage	$I_E = 10\text{ }\mu\text{A}, I_C = 0$	6.0	–	V
I_{BL}	Base Cutoff Current	$V_{CE} = 30\text{ V}, V_{EB} = 3\text{ V}$	–	50	nA
I_{CEX}	Collector Cut-Off Current	$V_{CE} = 30\text{ V}, V_{EB} = 3\text{ V}$	–	50	nA

ON CHARACTERISTICS (Note 3)

h_{FE}	DC Current Gain	$I_C = 0.1\text{ mA}, V_{CE} = 1.0\text{ V}$	40	–	–
		$I_C = 1.0\text{ mA}, V_{CE} = 1.0\text{ V}$	70	–	
		$I_C = 10\text{ mA}, V_{CE} = 1.0\text{ V}$	100	300	
		$I_C = 50\text{ mA}, V_{CE} = 1.0\text{ V}$	60	–	
		$I_C = 100\text{ mA}, V_{CE} = 1.0\text{ V}$	30	–	
$V_{CE(sat)}$	Collector – Emitter Saturation Voltage	$I_C = 10\text{ mA}, I_B = 1.0\text{ mA}$	–	0.2	V
		$I_C = 50.0\text{ mA}, I_B = 5.0\text{ mA}$	–	0.3	
$V_{BE(sat)}$	Base – Emitter Saturation Voltage	$I_C = 10.0\text{ mA}, I_B = 1.0\text{ mA}$	0.65	0.85	V
		$I_C = 50.0\text{ mA}, I_B = 5.0\text{ mA}$	–	0.95	

SMALL-SIGNAL CHARACTERISTICS

f_T	Current – Gain – Bandwidth Product	$I_C = 10\text{ mA}, V_{CE} = 20\text{ V}, f = 100\text{ MHz}$	300	–	MHz
C_{obo}	Output Capacitance	$V_{CB} = 5.0\text{ V}, I_E = 0, f = 100\text{ kHz}$	–	4.0	pF
C_{ibo}	Input Capacitance	$V_{EB} = 0.5\text{ V}, I_C = 0, f = 100\text{ kHz}$	–	8.0	pF
NF	Noise Figure	$I_C = 100\text{ }\mu\text{A}, V_{CE} = 5.0\text{ V}, R_S = 1.0\text{ k}\Omega, f = 10\text{ Hz to }15.7\text{ kHz}$	–	5.0	dB

SWITCHING CHARACTERISTICS

t_d	Delay Time	$V_{CC} = 3.0\text{ V}, V_{BE} = 0.5\text{ V}, I_C = 10\text{ mA}, I_{B1} = 1.0\text{ mA}$	–	35	ns
t_r	Rise Time		–	35	ns
t_s	Storage Time	$V_{CC} = 3.0\text{ V}, I_C = 10\text{ mA}, I_{B1} = I_{B2} = 1.0\text{ mA}$	–	200	ns
t_f	Fall Time		–	50	ns

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

3. Pulse Test: Pulse Width $\leq 300\text{ }\mu\text{s}$; Duty Cycle $\leq 2\%$.

TYPICAL PERFORMANCE CHARACTERISTICS

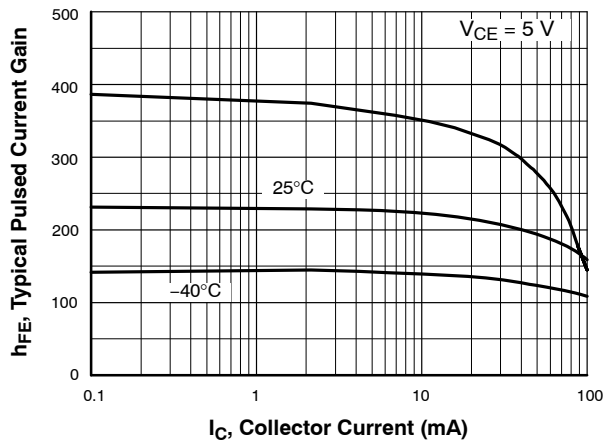


Figure 1. Typical Pulsed Current Gain vs. Collector Current

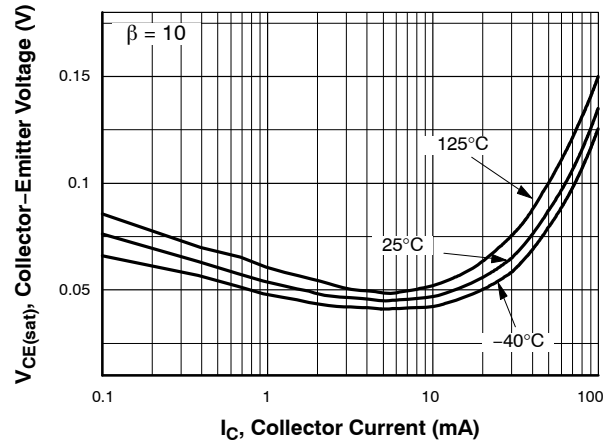


Figure 2. Collector-Emmitter Saturation Voltage vs. Collector Current

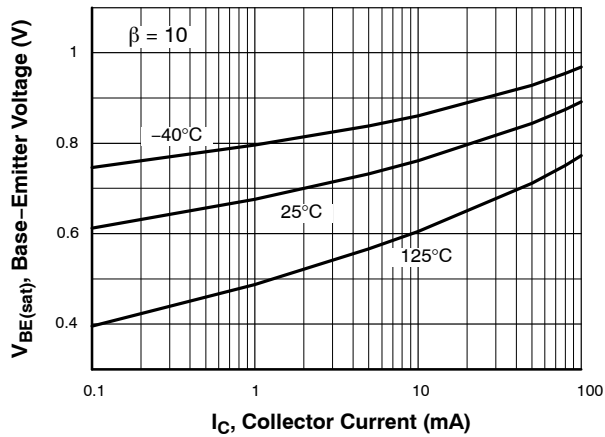


Figure 3. Base-Emmitter Saturation Voltage vs. Collector Current

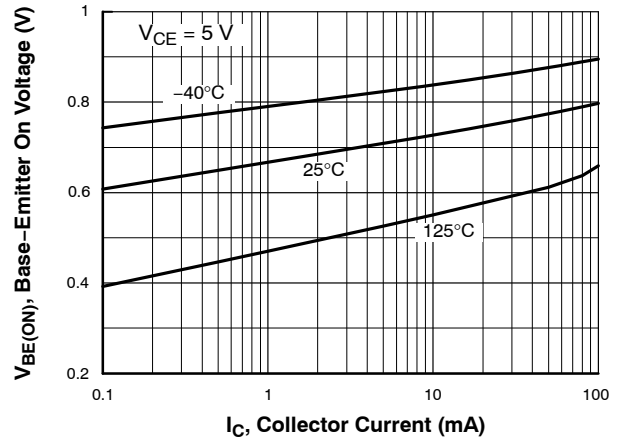


Figure 4. Base-Emmitter On Voltage vs. Collector Current

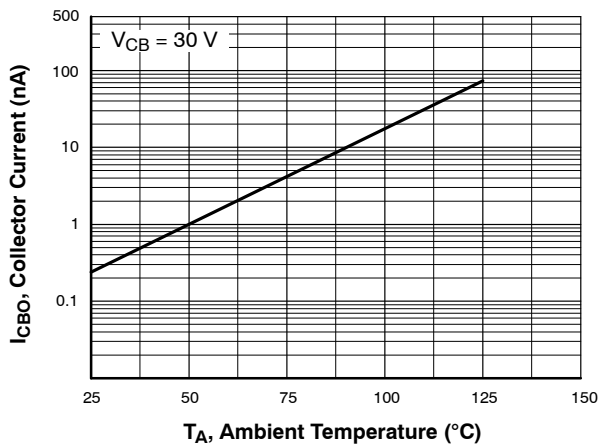


Figure 5. Collector Cut-Off Current vs. Ambient Temperature

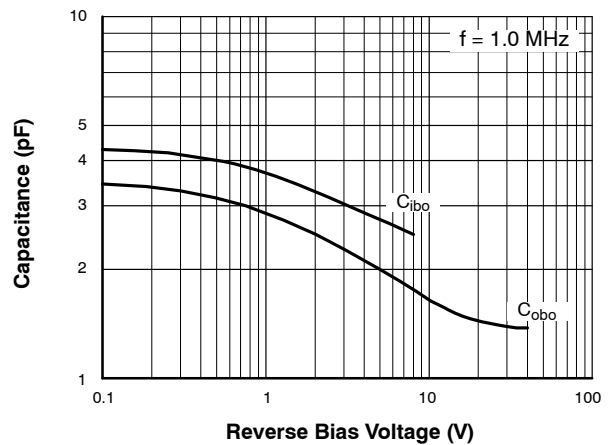


Figure 6. Capacitance vs. Reverse Bias Voltage

TYPICAL PERFORMANCE CHARACTERISTICS (Continued)

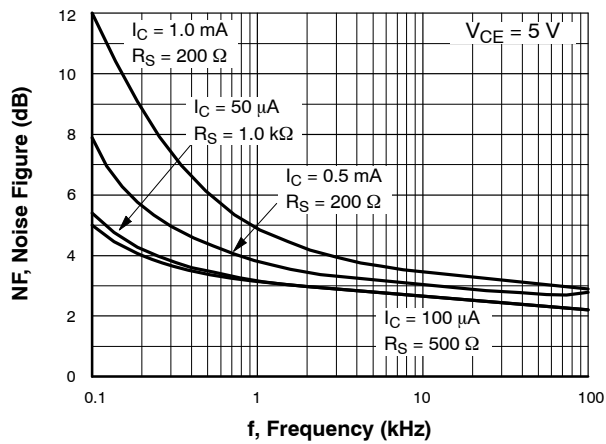


Figure 7. Noise Figure vs. Frequency

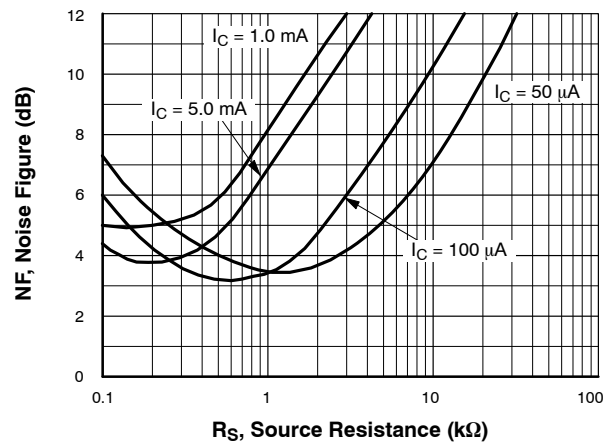


Figure 8. Noise Figure vs. Source Resistance

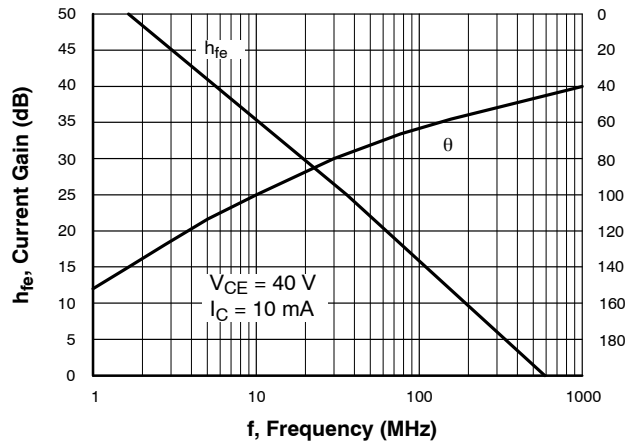


Figure 9. Current Gain and Phase Angle vs. Frequency

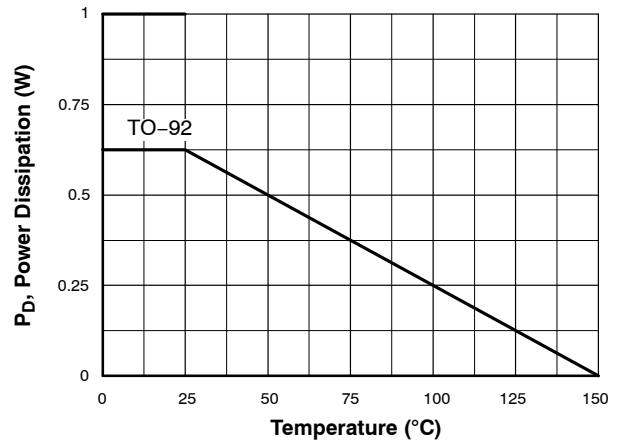


Figure 10. Power Dissipation vs. Ambient Temperature

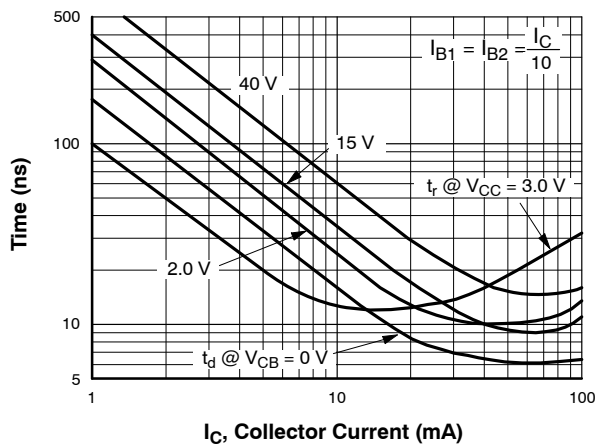


Figure 11. Turn-On Time vs. Collector Current

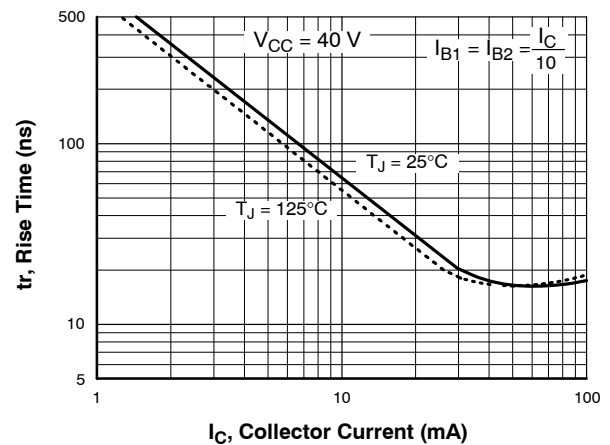


Figure 12. Rise Time vs. Collector Current

TYPICAL PERFORMANCE CHARACTERISTICS (Continued)

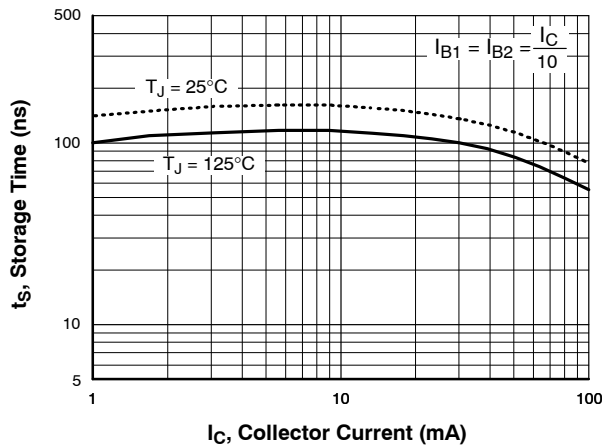


Figure 13. Storage Time vs. Collector Current

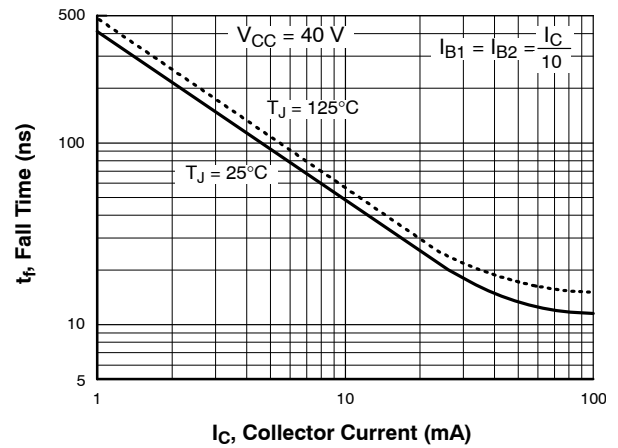


Figure 14. Fall Time vs. Collector Current

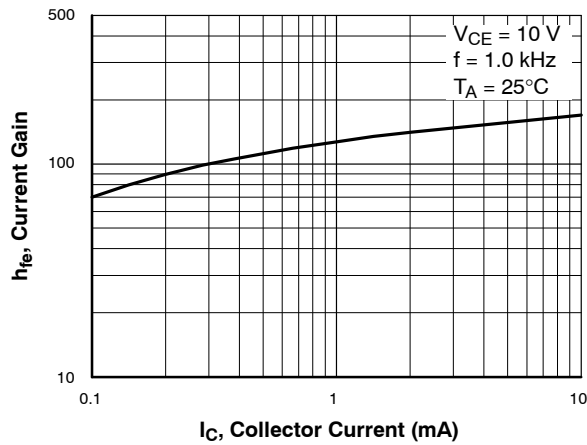


Figure 15. Current Gain

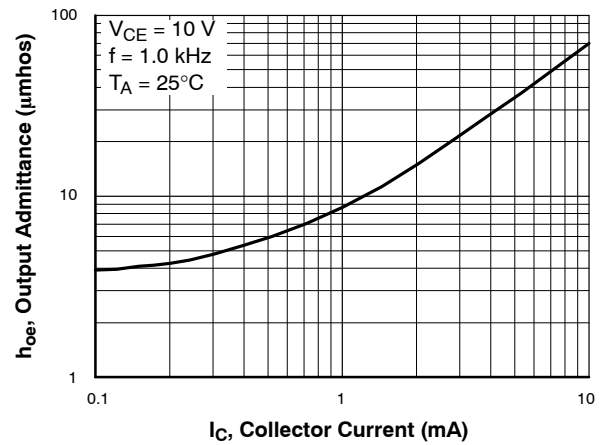


Figure 16. Output Admittance

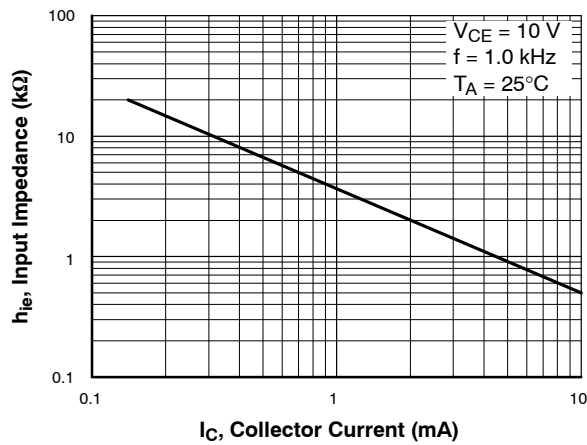


Figure 17. Input Impedance

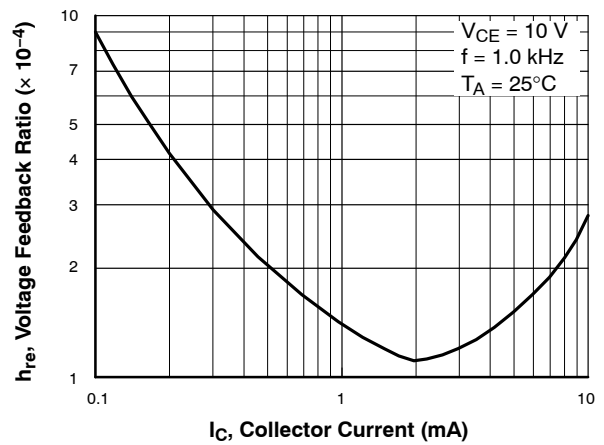


Figure 18. Voltage Feedback Ratio

2N3904

TEST CIRCUITS

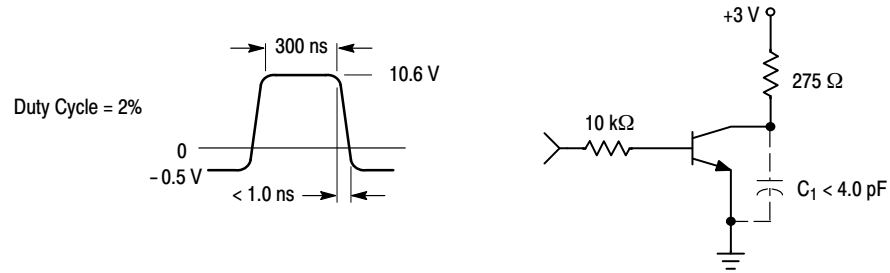


Figure 19. Delay and Rise Time Equivalent Test Circuit

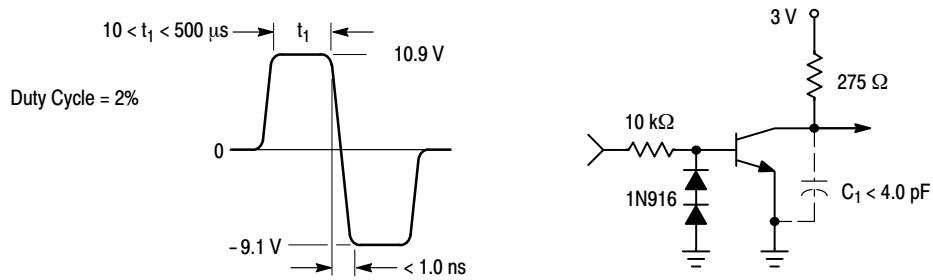


Figure 20. Storage and Fall Time Equivalent Test Circuit

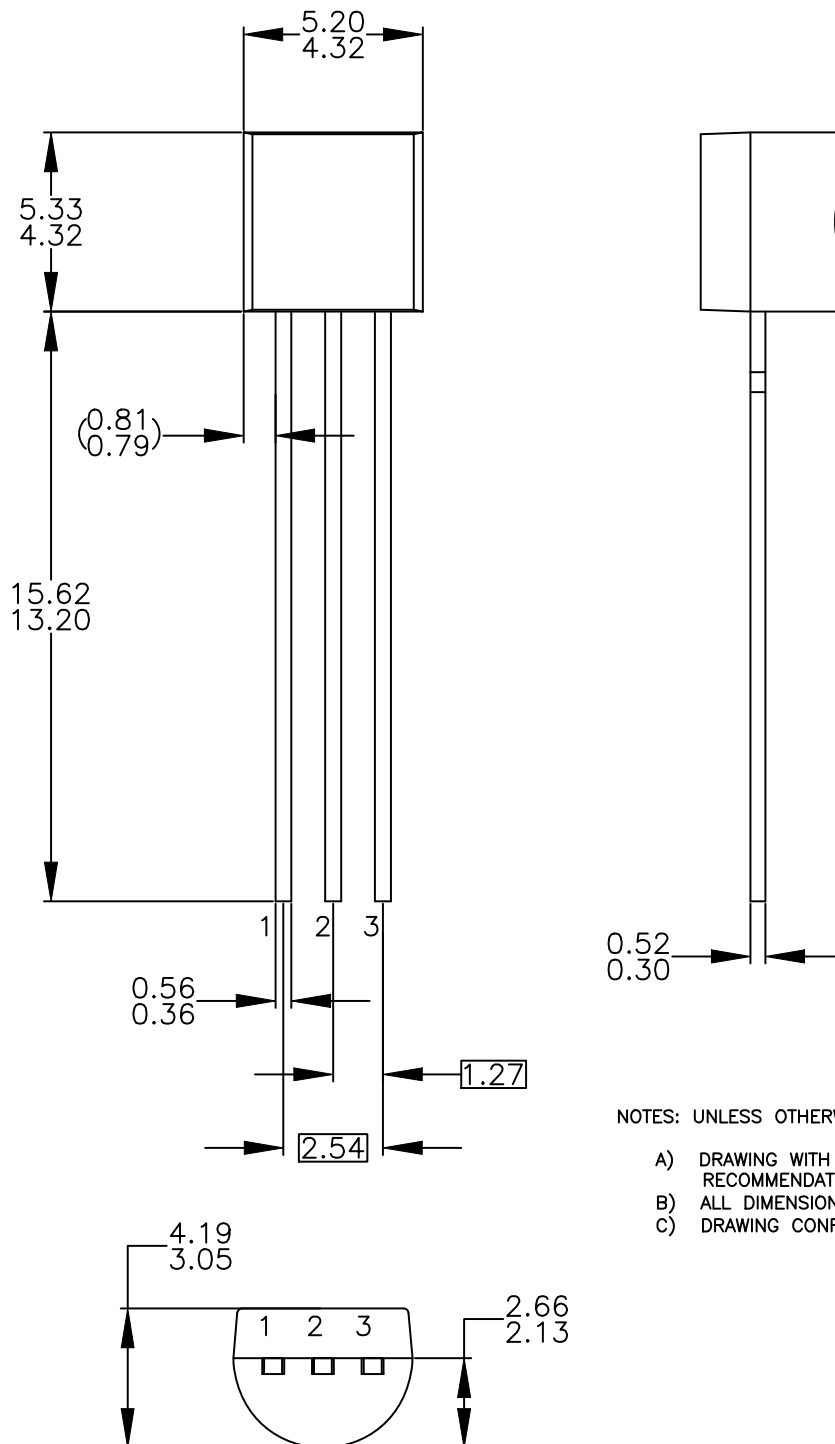
ORDERING INFORMATION

Device	Package	Shipping [†]
2N3904BU	TO-92-3 LF (Pb-Free)	10000 Units / Bulk Bag
2N3904TA	TO-92-3 LF (Pb-Free)	2000 Units / Fan-Fold
2N3904TAR	TO-92-3 LF (Pb-Free)	2000 Units / Fan-Fold
2N3904TF	TO-92-3 LF (Pb-Free)	2000 Units / Tape & Reel
2N3904TFR	TO-92-3 LF (Pb-Free)	2000 Units / Tape & Reel

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

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DATE 31 JUL 2016



NOTES: UNLESS OTHERWISE SPECIFIED

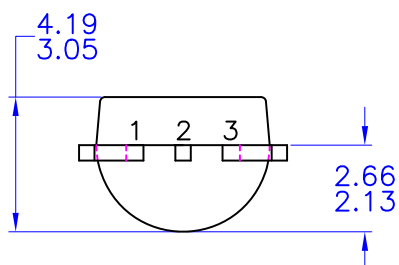
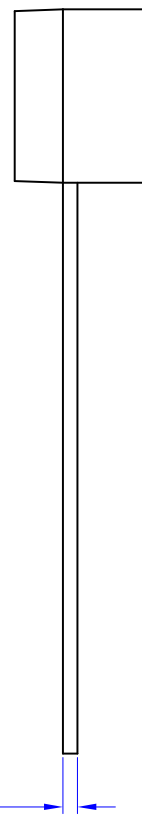
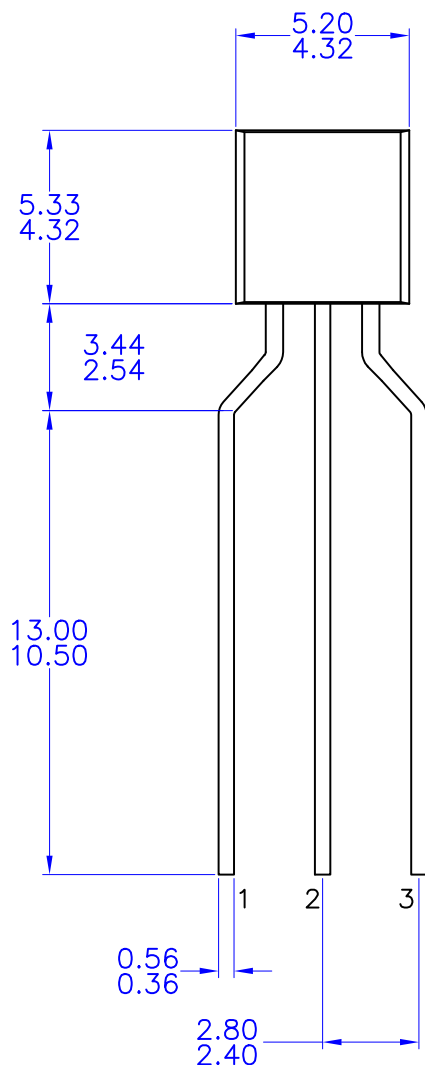
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